NSN 5961-01-128-4673

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-128-4673 **Inclosure Material:** Ceramic or plastic **Overall Length:** 0.785 inches **Overall Height:** 0.200 inches **Overall Width:** 0.280 inches **Component Name And Quantity:** 4 transistor **Mounting Method: Terminal Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 70.0 collector to base voltage/static/emitter open all transistor and 70.0 collector to emitter voltage, dc with base short-circuited to emitter all transistor and 45.0 collector to emitter voltage/static/base open all transistor and 6.0 emitter to base, rms all transistor **Current Rating Per Characteristic:** 1.50 amperes source cutoff current all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** All transistor junction pattern arrangement: npn **Terminal Type And Quantity:** 14 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No